

DESIGNING AMPLIFIERS? MELCOM SUPPLY WORLD LEADING RF & mmW AMPLIFIER COMPONENTS



GaN on Silicon
 Carbide Power
 Amplifiers

Output Power to 80 W

Flange & DIE Options Available
Gate Length Process 0.15 µm

ALTUM RF

- Power Amplifiers
- Distributed Amplifiers
- Low Noise Amplifiers
- DC 100 GHz, GaAs upto 4 W, GaN 5-30 W
- DC to 40 GHz , Output Power to +28 dBm
- Noise figure 2.5 dB
 ITAR Free

DC - 40 GHz



- Low Noise Amplifiers
- Driver Amplifiers
- Amplifier Modules
- DC to 40 GHz, Typical Noise Figure 2.0 dB
- From DC to 24 GHz, Output Power +21.0 dBm
- DC to 20 GHz, Broadband Frequency Response



- Low Noise Amplifiers
- Power Amplifiers
- Broadband Amplifiers —
- Benchtop Amplifiers
- 18 to 1/0 GHz, Noise Figure 2.5 dB
- 17 to 110 GHz, Output Power up to +38 dBm
- DC to 65 GHz, Output Power to +30 dBm
- From 18 to 170 GHz, Output Power +35 dBm



- Directional Couplers
- Combiners/Dividers
- 90° & 180° Hybrids
- High Power From 5 W to 100 kW CW
- Frequency Range DC to 10 GHz
- SMT & Coxial Options



- Conical Inductors
- Coil Inductors
- Spiral Inductors
- Broadband to 67 GHz
- Fixed & Tuneable
- Up to 17 GHz
 QPL Availability



- Attenuators, Resistors, Terminations
- SMT, Flange, Coaxial
- AIN, BeO & CVD
 Diamond Substrates
- DC to 40 GHz
- Power Handling to 2 Kw Temp Range -55°C to +150°C



- Thermal/EMI Solutions
- Form-In Place Gaskets
- Metallised Plastics
- Heatsink Solutions
- Thermal Materials
- Provides size & weight advantage with increased PCB area
- Free of Charge Thermal Analysis to support your design development









MELCOM PROVIDES THE SOLUTION